
(1) Connector SMA2.9 is equivalent to "K Connector ${ }^{\circledR \text { " }}$, registered trademark of Anritsu

PICTURE


[^0]
## RF PERFORMANCES

| PART NUMBER | R5953----- | R5954----- | R595F----- | R5958----- |
| :---: | :---: | :---: | :---: | :---: |
| Frequency Range GHz | DC to 6 | DC to 20 | DC to 26.5 | DC to 40 |
| Impedance Ohms | 50 |  |  |  |
| Insertion Loss dB (Maximum) | $0.20+(0.45 / 26.5) \times$ frequency $(\mathrm{GHz})$ |  |  |  |
| Isolation dB (Minimum) | 85 | $\begin{aligned} & \mathrm{DC} \text { to } 6 \mathrm{GHz}: 85 \\ & 6 \text { to } 12.4 \mathrm{GHz}: 75 \\ & 12.4 \text { to } 20 \mathrm{GHz}: 65 \end{aligned}$ | DC to $6 \mathrm{GHz}: 85$ 6 to $12.4 \mathrm{GHz}: 75$ 12.4 to $20 \mathrm{GHz}: 65$ 20 to $26.5 \mathrm{GHz}: 60$ | $\begin{aligned} & \hline \text { DC to } 6 \mathrm{GHz}: 85 \\ & 6 \text { to } 12.4 \mathrm{GHz}: 75 \\ & 12.4 \text { to } 20 \mathrm{GHz}: 65 \\ & 20 \text { to } 26.5 \mathrm{GHz}: 60 \\ & 26.5 \text { to } 40 \mathrm{GHz}: 55 \end{aligned}$ |
| V.S.W.R. <br> (Maximum) | 1.15 | DC to $6 \mathrm{GHz}:$ 6 to $12.4 \mathrm{GHz}: 1.25$ 12.4 to $20 \mathrm{GHz}: 1.30$ | DC to $6 \mathrm{GHz}:$ 6 to $12.4 \mathrm{GHz}: 1.15$ 12.4 to $20 \mathrm{GHz}: 1.30$ 20 to $26.5 \mathrm{GHz}: 1.60$ | DC to $6 \mathrm{GHz}: 1.15$ 6 to $12.4 \mathrm{GHz}: 1.25$ 12.4 to $20 \mathrm{GHz}: 1.30$ 18 to $26.5 \mathrm{GHz}: 1.60$ 26.5 to $40 \mathrm{GHz}: 1.80$ |
| Third order Inter Modulation | -120 dBc typical (2 carriers 20W) |  |  |  |
| Repeatability (up to 10 million cycles measured at $25^{\circ} \mathrm{C}$ ) | 0.03 dB maximum |  |  | 0.05 dB maximum |



[^1]Technical Data Sheet
HIGH PERFORMANCE DP3T-SPDT SWITCHES PLATINUM Series


## ENVIRONMENTAL SPECIFICATIONS

| Operating temperature range ( ${ }^{\circ} \mathrm{C}$ ) | -25 to +75 |
| :---: | :---: |
| Storage temperature range ( ${ }^{\circ} \mathrm{C}$ ) | -55 to +85 |
| Temperature cycling (MIL-STD-202, Method 107D , Cond.A) ( ${ }^{\circ} \mathrm{C}$ ) | -55 to +85 (10 cycles) |
| Sine vibration operating (MIL STD 202 , Method 204D , Cond.D) | $10-2000 \mathrm{~Hz}, 20 \mathrm{~g}$ |
| Random vibration operating | 16.91 g (rms) 50-2000 Hz 3min/axis |
| Shock operating (MIL STD 202 , Method 213B, Cond.G) | $50 \mathrm{~g} / 11 \mathrm{~ms}$, sawtooth |
| Humidity operating | 15 to $95 \%$ relative humidity |
| Humidity storage (MIL STD 202, Method 106E, Cond.E) | $65^{\circ} \mathrm{C}, 95 \% \mathrm{RH}, 10$ days |
| Altitude operating | 15,000 feet (4,600 meters) |
| Altitude storage (MIL STD 202, Method 105C , Cond.B) | 50,000 feet ( 15,240 meters) |

[^2]
## SWITCH MODEL 1: NON TERMINATED SPDT SWITCH

The non-terminated SPDT switch is a single pole double throw switch. This switch is "break before make".

## RF SCHEMATIC DIAGRAM

## Position E1



## INDICATORS POSITION



State "11"

Standard drive option "1" (Positive common):

- Connect pin +Vcc to supply
- Select desired RF path by applying ground to the corresponding "Close" pin (Ex: ground pin E1 to switch to position E1. RF path 1-2 closed and RF path 2-3 open).
- To open desired path and close the new RF path, connect ground to the corresponding "close" pin (Ex: ground pin E2 to open RF path 1-2 and close RF path 2-3)


Solder pins


State "22"

## Position E2



## TTL drive option " 2 "

- Connect pin GND to ground.
- Connect pin +Vcc to supply
- Select (close) desired RF path by applying TTL "High " to the corresponding "drive" pin (Ex: apply TTL "High" to pin E1 to switch to position E1. RF path 1-2 closed and RF path 2-3 open).
- To open desired path and close the new RF path, apply TTL "High" to the "drive" pin which corresponds to the desired RF path.
(Ex: apply TTL "High" to pin E2 to open RF path 1-2 and close RF path 2-3).


D-Sub connector


## SWITCH MODEL 2: TERMINATED SPDT SWITCH

The-terminated SPDT switch is a single pole double throw switch. The unused ports are terminated into 50ohms. This switch is "break before make".

## RF SCHEMATIC DIAGRAM

Position E1


Position E2


## INDICATORS POSITION



State "11"

Standard drive option "1" (Positive common):

- Connect pin +Vcc to supply
- Select desired RF path by applying ground to the corresponding "Close" pin (Ex: ground pin E1 to switch to position E1. RF path 1-2 closed and RF path 2-3 open).
- To open desired path and close the new RF path, connect ground to the corresponding "close" pin (Ex: ground pin E2 to open RF path 1-2 and close RF path 2-3)


D-Sub connector


Solder pins


State "22"

TTL drive option " 2 "

- Connect pin GND to ground.
- Connect pin +Vcc to supply
- Select (close) desired RF path by applying TTL "High" to the corresponding "drive" pin (Ex: apply TTL "High" to pin E1 to switch to position E1. RF path 1-2 closed and RF path 2-3 open).
- To open desired path and close the new RF path, apply TTL "High" to the "drive" pin which corresponds to the desired RF path.
(Ex: apply TTL "High" to pin E2 to open RF path 1-2 and close RF path 2-3).


D-Sub connector
Solder pins

| PAGE 7/12 | ISSUE 05-11-18 | SERIES DP3T/SPDT | PART NUMBER R595 XXX XXX |
| :---: | :---: | :---: | :---: |
|  | with D-Sub con <br> 123 | All dimensions are in mi | [inches]. <br> Model SMA with solder pins |
| Mod $4 \times 3$ <br>  | 9 with D-Sub co |  | Model SMA2.9with solder pins |
| $4-40$ |  |  | TOP view - solder pins |

## SWITCH MODEL 3: TERMINATED 4 PORT BYPASS SWITCH

The terminated 4 port bypass switch can terminate into 50 ohms the device under test. These switches are "break before make".

## RF SCHEMATIC DIAGRAM

Position E1


## Position E2



## INDICATORS POSITION



State "11"

Standard drive option "1" (Positive common):

- Connect pin +Vcc to supply
- Select desired RF path by applying ground to the corresponding "Close" pin (Ex: ground pin E1 to switch to position E1. RF path 1-2 closed and RF path 2-3 open).
- To open desired path and close the new RF path, connect ground to the corresponding "close" pin (Ex: ground pin E2 to open RF path 1-2 and close RF path 2-3)


D-Sub connector


State "22"

TTL drive option " 2 "

- Connect pin GND to ground.
- Connect pin +Vcc to supply
- Select (close) desired RF path by applying TTL "High" to the corresponding "drive" pin (Ex: apply TTL "High" to pin E1 to switch to position E1. RF path 1-2 closed and RF path 2-3 open).
- To open desired path and close the new RF path, apply TTL "High" to the "drive" pin which corresponds to the desired RF path.
(Ex: apply TTL "High" to pin E2 to open RF path 1-2 and close RF path 2-3).


D-Sub connector
Solder pins


## SWITCH MODEL 4: NON TERMINATED 5 PORT DP3T SWITCH

The non-terminated 5 port DP3T switch can used as SPDT with high power terminations, as a bypass switch. In this application, the fifth port can be terminated externally with a high power termination. These switches are "break before make".

## RF SCHEMATIC DIAGRAM



## Position E2



## INDICATORS POSITION



State "11"

Standard drive option "1" (Positive common):

- Connect pin +Vcc to supply
- Select desired RF path by applying ground to the corresponding "Close" pin (Ex: ground pin E1 to switch to position E1. RF path 2-3and RF path 4-5 open).
- To open desired path and close the new RF path, connect ground to the corresponding "close" pin (Ex: ground pin E2 to open RF path 2-3 and 4-5 and close RF path 1-2 and 3-4)


D-Sub connector
Solder pins


State "22"

TTL drive option " 2 "

- Connect pin GND to ground.
- Connect pin +Vcc to supply
- Select (close) desired RF path by applying TTL "High" to the corresponding "drive" pin (Ex: apply TTL "High" to pin E1 to switch to position E1. RF path 2-3 and RF path 4-5 closed and RF path 1-2 and 3-4 open).
- To open desired path and close the new RF path, apply TTL "High" to the "drive" pin which corresponds to the desired RF path.
(Ex: apply TTL "High" to pin E2 to open RF path 2-3 and 45 and close RF path 1-2 and 3-4).


D-Sub connector
Solder pins


## POWER RATING CHART

This graph is based on the following conditions:

- Ambient temperature: $+25^{\circ} \mathrm{C}$
- Sea level
- V.S.W.R.: 1 and cold switching



## DERATING FACTOR VERSUS V.S.W.R.

The average power input must be reduced for load V.S.W.R. above 1.


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